



Linear Systems Ultra Low Leakage Low Drift Monolithic Dual JFET

The LS843 is a high-performance monolithic dual JFET featuring extremely low noise, tight offset voltage and low drift over temperature specifications, and is targeted for use in a wide range of precision instrumentation applications. The LS843 features a 1-mV offset and 5- μ V/ $^{\circ}$ C drift.

The 6 Pin SOT-23 package provides ease of manufacturing, and a lower cost assembly option.

(See Packaging Information).

LS843 Applications:

- Wideband Differential Amps
- High-Speed, Temp Compensated Single-Ended Input Amps
- High-Speed Comparators
- Impedance Converters and vibrations detectors.

ELECTRICAL CHARACTERISTICS @ 25°C (unless otherwise noted)

SYMBOL	CHARACTERISTICS	MIN.	TYP.	MAX.	UNITS	CONDITIONS		
BV_{GSS}	Breakdown Voltage	60	--	--	V	$V_{DS} = 0$ $I_D = 1nA$		
BV_{GGO}	Gate-To-Gate Breakdown	60	--	--	V	$I_G = 1nA$ $I_D = 0$ $I_S = 0$		
Y_{FS}	<u>TRANSCONDUCTANCE</u>							
Y_{FS}	Full Conduction	1500	--	--	μ mho	$V_{DG} = 15V$	$V_{GS} = 0V$	$f = 1kHz$
$ Y_{FS1-2}/Y_{FS} $	Typical Operation	1000	1500	--	μ mho	$V_{DG} = 15V$	$I_D = 500\mu A$	
$ Y_{FS1-2}/Y_{FS} $	Mismatch	--	0.6	3	%			
I_{DSS}	<u>DRAIN CURRENT</u>							
I_{DSS}	Full Conduction	1.5	5	15	mA	$V_{DG} = 15V$	$V_{GS} = 0V$	
$ I_{DSS1-2}/I_{DSS} $	Mismatch at Full Conduction	--	1	5	%			
$V_{GS(off)} \text{ or } V_p$	<u>GATE VOLTAGE</u>							
$V_{GS(off)} \text{ or } V_p$	Pinchoff voltage	1	--	3.5	V	$V_{DS} = 15V$	$I_D = 1nA$	
$V_{GS(on)}$	Operating Range	0.5	--	3.5	V	$V_{DS} = 15V$	$I_D = 500\mu A$	
$-I_Gmax.$	<u>GATE CURRENT</u>							
$-I_Gmax.$	Operating	--	15	50	pA	$V_{DG} = 15V$	$I_D = 500\mu A$	
$-I_Gmax.$	High Temperature	--	--	50	nA	$T_A = +125^{\circ}C$		
$-I_Gmax.$	Reduced V_{DG}	--	5	30	pA	$V_{DG} = 3V$	$I_D = 500\mu A$	
$-I_{GSSmax.}$	At Full Conduction	--	--	100	pA	$V_{DG} = 15V$	$V_{DS} = 0$	
Y_{OSS}	<u>OUTPUT CONDUCTANCE</u>							
Y_{OSS}	Full Conduction	--	--	20	μ mho	$V_{DG} = 15V$	$V_{GS} = 0V$	
Y_{OS}	Operating	--	0.2	2	μ mho	$V_{DG} = 15V$	$I_D = 500\mu A$	
$ Y_{OS1-2} $	Differential	--	0.02	0.2	μ mho			
CMR	<u>COMMON MODE REJECTION</u>							
	$-20 \log V_{GS1-2}/V_{DS} $	90	110	--			$\Delta V_{DS} = 10 \text{ to } 20V$	$I_D = 500\mu A$
	$-20 \log V_{GS1-2}/V_{DS} $	--	85	--			$\Delta V_{DS} = 5 \text{ to } 10V$	$I_D = 500\mu A$
NF	<u>NOISE</u>							
NF	Figure	--	--	0.5			$V_{DS} = 15V$	$V_{GS} = 0V$ $R_G = 10M\Omega$
e_n	Voltage	--	--	7			$f = 100Hz$	$NBW = 6Hz$
e_n		--	--	11			$V_{DS} = 15V$	$I_D = 500\mu A$ $f = 1KHz$ $NBW = 1Hz$
C_{ISS}	<u>CAPACITANCE</u>							
C_{ISS}	Input	--	--	8			$V_{DS} = 15V$	$I_D = 500\mu A$
C_{RSS}	Reverse Transfer	--	--	3				
C_{DD}	Drain-to-Drain	--	0.5	--			$V_{DG} = 15V$	$I_D = 500\mu A$

Note 1 - These ratings are limiting values above which the serviceability of any semiconductor may be impaired

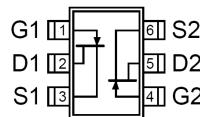
Available Packages:

LS843 / LS843 in SOT-23

LS843 / LS843 available as bare die

Please contact [Micross](#) for full package and die dimensions

SOT-23 TOP VIEW



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